Sheet	1	of	1	

Form PTO-1449 (REV. 8-83)	•		ATTY DO	OCKET NO.	APPLICATION NO. New U.S. Patent Application						
INFORMATION DISCLOSURE STATEMENT											
(Use several sheets if necessary)				APPLICANTS Etienne QUESNEL et al.							
				FILING DATE April 5, 2004							
	•	U.S.	PATE	ENT DOCL	JMENTS						
EXAMINER INITIAL		DOCUMENT NUMBER	DATE		NAME			CLASS	SUB CLASS		
/RM/	1	4,392,453	7/12/1983		LUSCHER						
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	_	FOREIC	SN PA	TENT DO	CUMENTS						
		DOCUMENT NUMBER	DATE		COUNTRY			CLASS	SUB CLASS		
/RM/	2	JP A 7-291790 w/ Abst & Trans	11/7/1995		Japan						
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		OTHER DOCUMENTS (Inc	cludin	g Author,	Title, Date, Pertinent Pag	es, etc.)					
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EXAMINER /Rodney Mcdonald/						DATE CONSIDERED 03/26/2007					
Examiner: Initial if citation considered, whether or not citation is in conformance with M.P.E.P. 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.											

Date: April 5, 2004